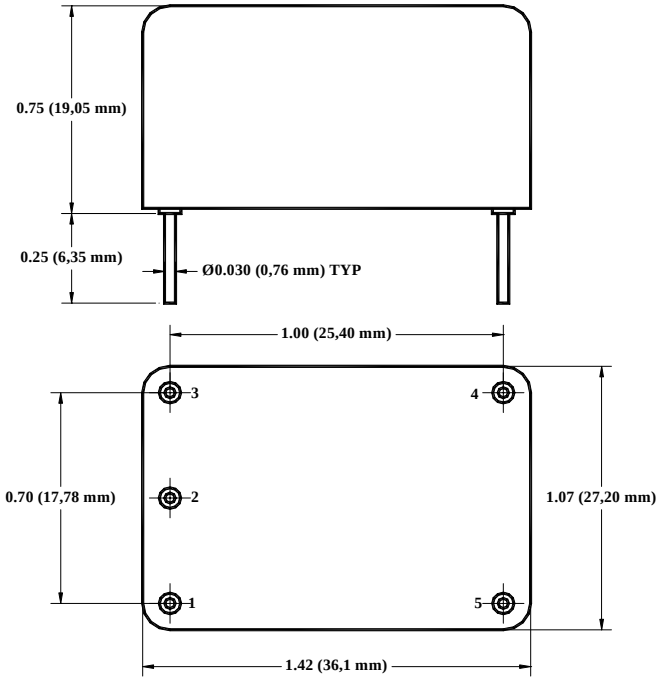
Rev. F

OM-X8GXXXXX-X Series
HF/UHF OCXO Low Power

Description: The OM-X8GXXXXX Series of Oven Controlled Crystal Oscillators (OCXO) provides High and Ultra High Frequency with SC-cut stability performance, extremely low phase noise and power consumption, with either CMOS or Sine-wave output in a standard 1.4x1" package – "Europack".



Features

- **Very Low Power Consumption**
- **Very Low Phase Noise**
- **Excellent SC-cut Frequency Stability**
- **Ultra High Frequency – up to 1 GHz**
- **CMOS, Sine-Wave outputs available**
- **Stratum3E available**

Creating a Part Number

OM – X 8G X X XX X - X - FREQ

Package Code
OM 5 pin 26 x 27x19mm high

Supply Voltage

Code	Specification
0	5V ±5%
A	3.3V ±5%

OCXO/OCVCXO Option

Code	Specification
X	No V. Control
V	W/ V. Control

Output Type

Code	Specification
C	CMOS
S	Sine-wave

Temperature Stability

Code	Specification
17	$1x10^{-7}$
58	$5x10^{-8}$
28	$2x10^{-8}$
18	$1x10^{-8}$
YZ	$Yx10^{-Z}$

Temperature Range

Code	Specification
A	0°C to 50°C
B	0°C to 70°C
C	-20°C to 70°C
D	-40°C to 85°C
E	-10°C to 60°C
F	-40°C to 80°C
G	-30°C to 70°C

Environmental

Code	Specification
L	Contains a level of lead that is in excess of RoHS directive and is not designed for reflow
R	RoHS compliant, not designed for reflow

NEL FREQUENCY CONTROLS, INC.
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Specifications

Parameter	Symb	Condition	Min	Typ	Max	Unit	Note
Absolute Maximum Ratings							
Input Break Down Voltage	Vcc		-0.5		5.5	V	
Storage temp.	Ts		-40		85	° C	
Contr. Voltage	Vc		1		9	V	
Electrical							
Frequency Range	F	CMOS Sine-wave	30 30		200 1,000	MHz	
Input Voltage	Vcc		3.135 4.75	3.30 5.0	3.465 5.25	V	A 0
Input Current	Icc				90 160	mA	@ 100 MHz, 3.3V @ 622 MHz, 3.3V
Frequency Stability	ΔF/F	vs. Temperature vs. Vcc aging		±50 ±2 ±0.1 ±0.5		ppb ppb/V ppm/year ppm	See chart First Year 15 years
Calibration	ΔF/F	As shipped, 25ºC		±0.1		ppm	
Load		CMOS Sine	15pF/10KOhm Internally AC-coupled 50 Ohm				
Duty cycle		@50%	45	50	55	%	CMOS
Rise/Fall time	Tr/Tf	20 to 80 %		3		ns	CMOS
Logic "1" level	Voh	CMOS	0.9Vcc			V	
Logic "0" level	Vol	CMOS			0.1Vcc	V	
Output power	P	Sinewave Into 50 Ohm	0 4	3 7		dBm	3.3V 5.0V
Start up time	Ts			2	10	ms	
Phase jitter		1σ		0.4 0.2	1 0.4	ps	100 Hz to 20 MHz 12 KHz to 20 MHz
Subharmonics		Sine CMOS, Sine		-45	-40 none	dBc	F>250MHz F< 250 MHz
Spurious					-60	dBc	
Harmonics		Sine-wave		-30	-25	dBc	
SSB Phase Noise		@10 Hz @100 Hz @1 KHz @10 KHz @100 KHz		-100 -120 -140 -160 -165		dBc/Hz	@100 MHz
SSB Phase Noise		@10 Hz @100 Hz @1 KHz @10 KHz @100 KHz		-80 -90 -120 -145 -150		dBc/Hz	@622 MHz; Sine
Input Impedance			> 10KOhm				
Control voltage	Vc		0		4.0	V	Vcc code “0”
			0		2.8	V	Vcc code “A”
Modulation bandwidth	MB			2Hz			Contact Factory for wider MB
Deviation		0V to Vc max	±0.5	±1.0		ppm	

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Environmental and Mechanical

Operating temp. range	0°C to 70°C , -40°C to 85°C, see chart, page 1
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. E
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A
Vibration	Per MIL-STD-883, Method 2007, Cond. A
Soldering Conditions	260°C for 10 s leads only
Hermetic Seal	Leak rate less than $5x10^{-8}$ atm.cc/s of helium

Electrical Connections

Pin Out	Pin #1- Voltage Control ; Pin #2 – Vref ; Pin #3 – Vcc; Pin#4 – Output, CMOS or Sine; Pin#5 - GND

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